General Description

The MAX9777/MAX9778 combine a stereo 3W bridgetied load (BTL) audio power amplifier, stereo singleended (SE) headphone amplifier, headphone sensing, and a 2:1 input multiplexer all in a tiny 28-pin thin QFN package. These devices operate from a single 4.5V to 5.5V supply and feature an industry-leading 100dB PSRR, allowing these devices to operate from noisy supplies without the addition of a linear regulator. An ultra-low 0.002% THD+N ensures clean, low-distortion amplification of the audio signal. Patented click-andpop suppression minimizes audible transients on power and shutdown cycles. Power-saving features include low 4mV Vos (minimizes DC current drain through the speakers), low 13mA supply current, and a 10µA shutdown mode. A MUTE function allows the outputs to be quickly enabled or disabled.

A headphone sense input detects the presence of a headphone jack and automatically configures the amplifiers for either speaker or headphone mode. In speaker mode, the amplifiers can deliver up to 3W of continuous average power into a 3Ω load. In headphone mode, the amplifier can deliver up to 200mW of continuous average power into a 16Ω load. The gain of the amplifiers is externally set, allowing maximum flexibility in optimizing output levels for a given load. The amplifiers also feature a 2:1 input multiplexer, allowing multiple audio sources to be selected. The multiplexer can also be used to compensate for limitations in the frequency response of the loud speakers by selecting an external equalizer network. The various functions are controlled by either an I²C[†]-compatible (MAX9777) or simple parallel control interface (MAX9778).

The MAX9777/MAX9778 are available in a thermally efficient 28-pin thin QFN package (5mm x 5mm x 0.8mm). These devices have thermal-overload protection (OVP) and are specified over the extended -40° C to $+85^{\circ}$ C temperature range.

Notebooks	PC Audio Peripherals
Portable DVD Players	Camcorders
Tablet PCs	Multimedia Monitor

[†]Purchase of I²C components from Maxim Integrated Products, Inc., or one of its sublicensed Associate Companies, conveys a license under the Philips I²C Patent Rights to use these components in an I²C system, provided that the system conforms to the I²C Standard Specification defined by Philips.

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

Applications

Features

- Industry-Leading, Ultra-High 100dB PSRR
- ♦ 3W BTL Stereo Speaker Amplifier
- 200mW Stereo Headphone Amplifier
- ♦ Low 0.002% THD+N
- Patented Click-and-Pop Suppression
- ESD-Protected Outputs
- Low Quiescent Current: 13mA
- ◆ Low-Power Shutdown Mode: 10µA
- ♦ MUTE Function
- Headphone Sense Input
- Stereo 2:1 Input Multiplexer
- Optional 2-Wire, I²C-Compatible or Parallel Interface
- Tiny 28-Pin Thin QFN (5mm x 5mm x 0.8mm) Package

_Ordering Information

PART	CONTROL INTERFACE	PIN- PACKAGE	PKG CODE
MAX9777ETI+	I ² C Compatible	28 Thin QFN-EP*	T2855-6
MAX9778ETI+	Parallel	28 Thin QFN-EP*	T2855-6

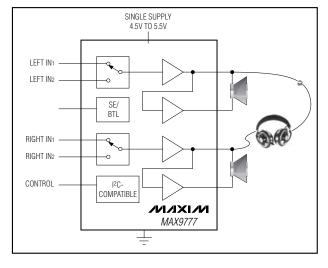
Note: All devices are specified over the -40°C to +85°C operating temperature range.

+Denotes lead-free package.

*EP = Exposed paddle.

Pin Configurations and Functional Diagrams appear at end of data sheet.

_Simplified Block Diagram



MAX9777/MAX9778

_ Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

V _{DD} to GND	+6V
PV _{DD} to V _{DD}	±0.3V
PGND to GND	±0.3V
All Other Pins to GND	0.3V to (V _{DD} + 0.3V)
Continuous Input Current (into any pin ex	cept power-supply
and output pins)	±20mA
OUT Short Circuit to GND, VDD	10s
Short Circuit Between OUT_+ and OUT	Continuous

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
28-Pin TQFN, Multilayer Board	
(derate 34.5mW/°C above +70°C)	2758.6mW
Operating Temperature Range	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{DD} = PV_{DD} = 5.0V, \text{GND} = PGND = 0V, V_{\overline{SHDN}} = 5V, C_{BIAS} = 1\mu\text{F}, R_{IN} = R_F = 15k\Omega, R_L = \infty$. TA = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at TA = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS	
Supply Voltage Range	V _{DD} /PV _{DD}	Inferred from PSRR test			4.5		5.5	V
Quiescent Supply Current	Supply Current . BTL mode, HPS = 0V, MAX9777/MAX9778		BTL mode, HPS = 0V, MAX9777/MAX9778			13	32	
(I _{VDD} + I _{PVDD})	IDD	Single-ended mode, HPS = V_{DD}			7	18	mA	
Shutdown Current	ISHDN	SHDN = GND				10	50	μA
Switching Time	tsw	Gain or input switch	ning			10		μs
Turn-On Time	tau	$C_{BIAS} = 1 \mu F$				300		
Tum-On Time	ton	$C_{BIAS} = 0.1 \mu F$				30		ms
Thermal Shutdown Threshold						+160		°C
Thermal Shutdown Hysteresis						15		°C
OUTPUT AMPLIFIERS (SPEAKI	ER MODE, HI	PS = GND)						
Output Offset Voltage	VOS	OUT_+ - OUT, A _V = 1V/V			±4	±32	mV	
Power-Supply Rejection Ratio (Note 2)	PSRR	$V_{DD} = 4.5V$ to 5.5V			75	100		
		$f = 1 kHz$, $V_{RIPPLE} = 200 mV_{P-P}$				82		dB
		$f = 20kHz, V_{RIPPLE} = 200mV_{P-P}$			70			
		f _{IN} = 1kHz,	$R_L = 8$	Ω		1.4		
Output Power	Pout	THD+N < 1%,	$R_L = 4\Omega$			2.6		W
		$T_A = +25^{\circ}C$	$R_L = 3\Omega$			3		
Total Harmonic Distortion Plus	THD+N	f _{IN} = 1kHz, BW =	Pout =	= 1W, $R_L = 8\Omega$		0.005		%
Noise	IIID+N	22Hz to 22kHz	Pout =	= 2W, R_L = 4 Ω		0.01		/0
Signal-to-Noise Ratio	SNR	$R_L = 8\Omega$, $P_{OUT} = 1$	$R_L = 8\Omega$, $P_{OUT} = 1W$, $BW = 22Hz$ to $22kHz$			95		dB
Slew Rate	SR					1.6		V/µs
Maximum Capacitive Load Drive	CL	No sustained oscillations				1		nF
Crosstalk		$f_{IN} = 10 kHz$				73		dB
Click/Pop Level	Кср	Peak voltage, A-we 32 samples per sec	<u> </u>	Into shutdown		-50		dBV
		(Notes 2, 6)		Out of shutdown		-65		

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = PV_{DD} = 5.0V, GND = PGND = 0V, V_{\overline{SHDN}} = 5V, C_{BIAS} = 1\mu F, R_{IN} = R_F = 15k\Omega, R_L = \infty$. T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS			MIN	ТҮР	MAX	UNITS
OUTPUT AMPLIFIERS (HEADPH	IONE MODE	, HPS = V _{DD})						
		$V_{DD} = 4.5V$ to 5.5V		75	106			
Power-Supply Rejection Ratio (Note 2)	PSRR	f = 1kHz, VRIPPLE = 20) 0mVF	p-b		88		dB
		f = 20kHz, V _{RIPPLE} = 2	200m\	VP-P		76		
Output Power	Bout	$f_{IN} = 1 kHz, THD+N <$	RL =	= 32Ω		88		mW
Output Fower	Pout	1%, T _A = +25°C	RL =	= 16Ω		200		11100
Total Harmonic Distortion Plus	THD+N	f _{IN} = 1kHz,		T = 60mW, 32Ω		0.002		01
Noise	I HD+N	BW = 22Hz to 22kHz	00	_T = 125mW, = 16Ω		0.002		%
Signal-to-Noise Ratio	SNR	$R_L = 32\Omega$, BW = 22Hz to 22kHz, VOUT = 1V _{RMS}			92		dB	
Slew Rate	SR					1.8		V/µs
Maximum Capacitive Load Drive	CL	No sustained oscillations				2		nF
Crosstalk		f _{IN} = 10kHz				78		dB
BIAS VOLTAGE (BIAS)								
BIAS Voltage	VBIAS				2.35	2.5	2.65	V
Output Resistance	RBIAS					50		kΩ
DIGITAL INPUTS (MUTE, SHDN	, HPS_EN, G	AINA/B, IN1/2)						
Input-Voltage High	VIH				2			V
Input-Voltage Low	VIL						0.8	V
Input Leakage Current	I _{IN}						±1	μA
HEADPHONE SENSE INPUT (HI	PS)							
Input-Voltage High	VIH				0.9 x V _{DD}			V
Input-Voltage Low	VIL						0.7 x V _{DD}	V
Input Leakage Current	I _{IN}						±1	μA
Click/Pop Level	Кср	Peak voltage, A-weigh 32 samples per secor		Into shutdown		-70		dBV
, , , ,		(Notes 2, 4)		Out of shutdown		-52		

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = PV_{DD} = 5.0V, GND = PGND = 0V, V_{SHDN} = 5V, C_{BIAS} = 1\mu$ F, R_{IN} = R_F = 15k Ω , R_L = ∞. T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	МАХ	UNITS
2-WIRE SERIAL INTERFACE (S	CL, SDA, AD	D, INT) (MAX9777)	·			•
Input-Voltage High	VIH		2.6			V
Input-Voltage Low	VIL				0.8	V
Input Hysteresis				0.2		V
Input High Leakage Current	IIН	$V_{IN} = 5V$			±1	μA
Input Low Leakage Current	١ _١ ٢	$V_{IN} = 0V$			±1	μA
Input Capacitance	CIN			10		pF
Output-Voltage Low	Vol	I _{OL} = 3mA			0.4	V
Output Current High	IOH	$V_{OH} = 5V$			1	μA
TIMING CHARACTERISTICS (M	IAX9777)					
Serial Clock Frequency	fscl				400	kHz
Bus Free Time Between STOP and START Conditions	tBUF		1.3			μs
START Condition Hold Time	thd:sta		0.6			μs
START Condition Setup Time	tsu:sta		0.6			μs
Clock Period Low	tLOW		1.3			μs
Clock Period High	thigh		0.6			μs
Data Setup Time	tsu:dat		100			ns
Data Hold Time	thd:dat	(Note 3)	0		0.9	μs
Receive SCL/SDA Rise Time	tr	(Note 4)	20 + 0.1C _B		300	ns
Receive SCL/SDA Fall Time	t _f	(Note 4)	20 + 0.1C _B		300	ns
Transmit SDA Fall Time	t _f	(Note 4)	20 + 0.1C _B		250	ns
Pulse Width of Suppressed Spike	tsp	(Note 5)		50		ns

Note 1: All devices are 100% production tested at +25°C. All temperature limits are guaranteed by design.

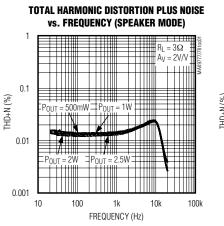
Note 2: Inputs AC-coupled to GND.

Note 3: A master device must provide a hold time of at least 300ns for the SDA signal to bridge the undefined region of SCL's falling edge.

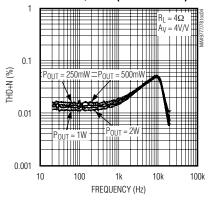
Note 4: C_B = total capacitance of one of the bus lines in picofarads. Device tested with C_B = 400pF. 1k Ω pullup resistors connected from SDA/SCL to V_{DD}.

Note 5: Input filters on SDA, SCL, and ADD suppress noise spikes of less than 50ns.

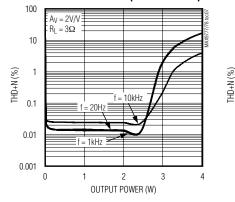
Note 6: Headphone mode testing performed with 32Ω resistive load connected to GND. Speaker mode testing performed with 8Ω resistive load connected to GND. Mode transitions are controlled by SHDN. KCP level is calculated as 20log[(peak voltage during mode transition, no input signal)/1V_{RMS}]. Units are expressed in dBV.



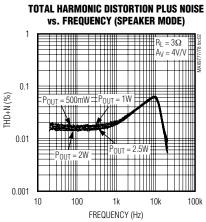
TOTAL HARMONIC DISTORTION PLUS NOISE vs. Frequency (Speaker Mode)



TOTAL HARMONIC DISTORTION PLUS NOISE vs. Output Power (Speaker Mode)

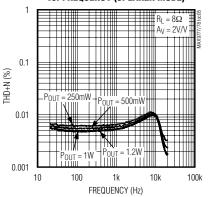


Typical Operating Characteristics

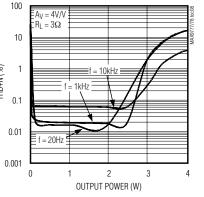


(VDD = PVDD = 5V, GND = PGND = 0V, VSHDN = 5V, CBIAS = 1µF, TA = +25°C, unless otherwise noted.)

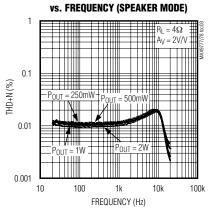
TOTAL HARMONIC DISTORTION PLUS NOISE vs. Frequency (Speaker Mode)



TOTAL HARMONIC DISTORTION PLUS NOISE vs. Output Power (Speaker Mode)

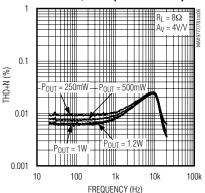


TOTAL HARMONIC DISTORTION PLUS NOISE

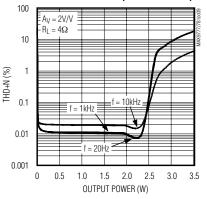


MAX9777/MAX9778

TOTAL HARMONIC DISTORTION PLUS NOISE vs. Frequency (Speaker Mode)

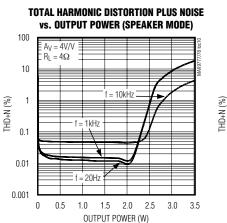


TOTAL HARMONIC DISTORTION PLUS NOISE vs. Output Power (Speaker Mode)

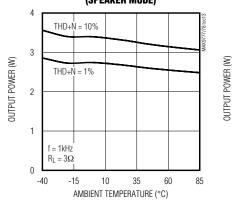


Typical Operating Characteristics (continued)

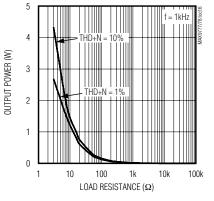
 $(V_{DD} = PV_{DD} = 5V, GND = PGND = 0V, V_{\overline{SHDN}} = 5V, C_{BIAS} = 1\mu F, T_A = +25^{\circ}C, unless otherwise noted.)$



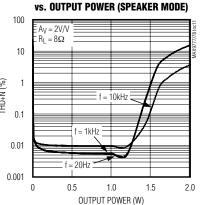




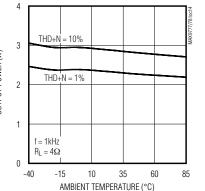
OUTPUT POWER vs. LOAD RESISTANCE (SPEAKER MODE)



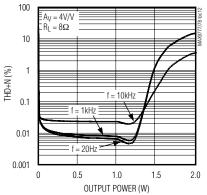




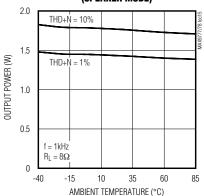
OUTPUT POWER vs. AMBIENT TEMPERATURE (SPEAKER MODE)



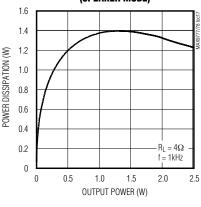
TOTAL HARMONIC DISTORTION PLUS NOISE vs. Output Power (Speaker Mode)



OUTPUT POWER vs. AMBIENT TEMPERATURE (SPEAKER MODE)



POWER DISSIPATION vs. OUTPUT POWER (SPEAKER MODE)

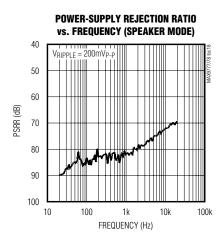


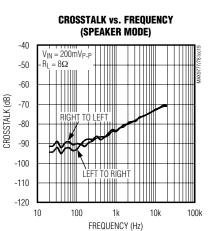
M/X/M

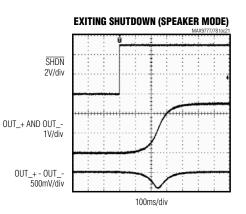
MAX9777/MAX9778

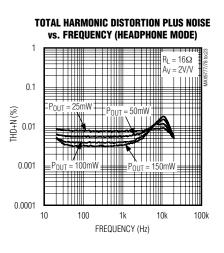
Typical Operating Characteristics (continued)

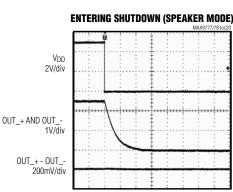
 $(V_{DD} = PV_{DD} = 5V, GND = PGND = 0V, V_{SHDN} = 5V, C_{BIAS} = 1\mu F, T_A = +25^{\circ}C, unless otherwise noted.)$



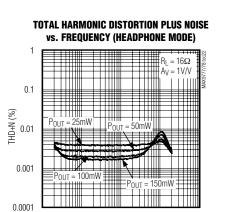








400ms/div



1k

FREQUENCY (Hz)

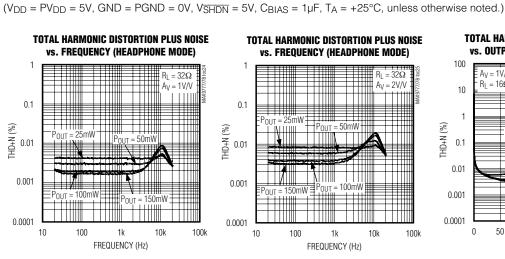
10k

100

10

100

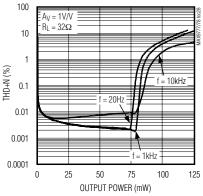
MAX9777/MAX9778



TOTAL HARMONIC DISTORTION PLUS NOISE vs. FREQUENCY (HEADPHONE MODE) R = 32Ω $A_V = 2V/V$ 01 25mW 50mW 0.01

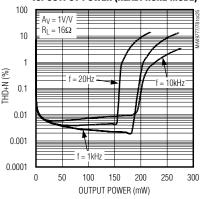
NHIII 0.001 100mW OUT 0.0001 10 100 1k 10k 100k FREQUENCY (Hz)

TOTAL HARMONIC DISTORTION PLUS NOISE vs. OUTPUT POWER (HEADPHONE MODE)

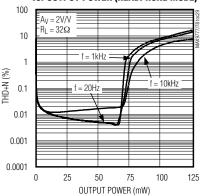


TOTAL HARMONIC DISTORTION PLUS NOISE vs. OUTPUT POWER (HEADPHONE MODE)

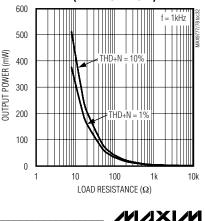
Typical Operating Characteristics (continued)



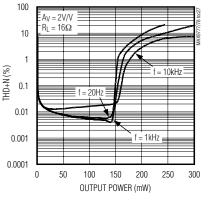
TOTAL HARMONIC DISTORTION PLUS NOISE vs. OUTPUT POWER (HEADPHONE MODE)



OUTPUT POWER vs. LOAD RESISTANCE (HEADPHONE MODE)

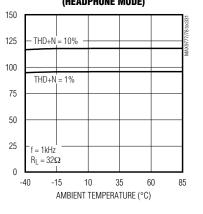


TOTAL HARMONIC DISTORTION PLUS NOISE vs. OUTPUT POWER (HEADPHONE MODE)



(HEADPHONE MODE)







OUTPUT POWER (mW)

85

60

(HEADPHONE MODE)

8

300

250

200

150

100

50

0

-40

OUTPUT POWER (mW)

THD+N = 10%

THD+N = 1%

f = 1kHz

 $R_I = 16\Omega$

-15

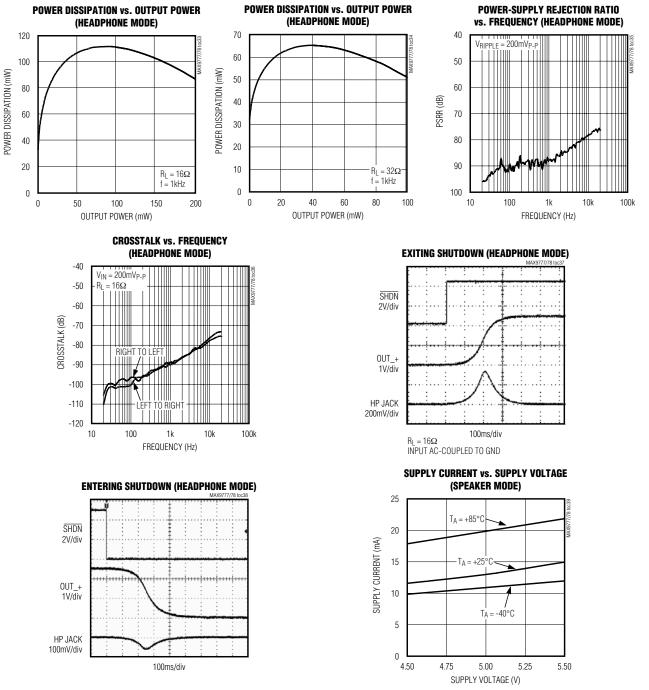
10

AMBIENT TEMPERATURE (°C)

35

Typical Operating Characteristics (continued)

(V_{DD} = PV_{DD} = 5V, GND = PGND = 0V, V_{SHDN} = 5V, C_{BIAS} = 1µF, T_A = +25°C, unless otherwise noted.)

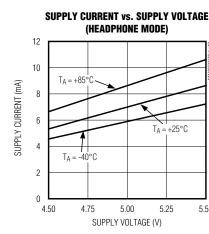


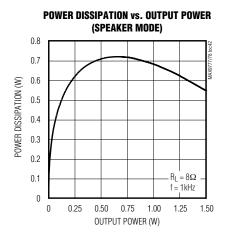
MAX9777/MAX9778

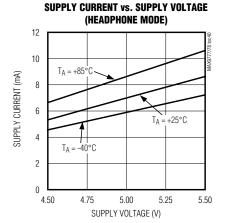
Typical Operating Characteristics (continued)

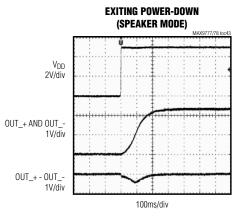
(V_{DD} = PV_{DD} = 5V, GND = PGND = 0V, V_{SHDN} = 5V, C_{BIAS} = 1µF, T_A = +25°C, unless otherwise noted.)

5.50









Pin Description

PI	PIN		EUNOTION			
MAX9777			FUNCTION			
1		SDA	Serial Data I/O			
2	_	ĪNT	Interrupt Output			
3, 4	3, 4	V _{DD}	Power-Supply Input			
5	5	INL1	Left-Channel Input 1			
6	6	INL2	Left-Channel Input 2			
7	7	GAINLA	Left-Channel Gain Set A			
8	8	GAINLB	Left-Channel Gain Set B			
9, 13, 23, 27	9, 13, 23, 27	PGND	Power Ground. Connect to GND.			
10	10	OUTL+	Left-Channel Bridged Amplifier Positive Output. OUTL+ also serves as the left-channel headphone amplifier output.			
11, 25	11, 25	PV _{DD}	Output Amplifier Power Supply			
12	12	OUTL-	Left-Channel Bridged Amplifier Negative Output			
14	14	SHDN	Active-Low Shutdown Input. Connect SHDN to VDD for normal operation.			
15	_	ADD	Address Select. A logic-high sets the address LSB to 1, a logic-low sets the address LSB to zero.			
16	16	HPS	Headphone Sense Input. A logic-high configures the device as a single ended headphone amp. A logic-low configures the device as a BTL speaker amp.			
17	17	BIAS	DC Bias Bypass Terminal. See the <i>BIAS Capacitor</i> section for capacitor selection. Connect C _{BIAS} from BIAS to GND.			
18	18	GND	Ground. Connect to PGND.			
19	19	INR1	Right-Channel Input 1			
20	20	INR2	Right-Channel Input 2			
21	21	GAINRA	Right-Channel Gain Set A			
22	22	GAINRB	Right-Channel Gain Set B			
24	24	OUTR+	Right-Channel Bridged Amplifier Positive Output. OUTR+ also serves as the right-channel headphone amplifier output.			
26	26	OUTR-	Right-Channel Bridged Amplifier Negative Output			
28	_	SCL	Serial Clock Line			
	1	MUTE	Active-High Mute Input			
_	2	HPS_EN	Headphone Enable. A logic-high enables HPS. A logic-low disables HPS and the device is always configured as a BTL speaker amplifier.			
	15	GAINĀ/B	Gain Select. A logic-low selects the gain set by GAIN_A. A logic-high selects the gain set by GAIN_B.			
_	28	IN1/2	Input Select. A logic-low selects amplifier input 1. A logic-high selects amplifier input 2.			
EP	EP	EP	Exposed Paddle. Connect to GND.			

MAX9777/MAX9778

_Detailed Description

The MAX9777/MAX9778 feature 3W BTL speaker amplifiers, 200mW headphone amplifiers, input multiplexers, headphone sensing, and comprehensive clickand-pop suppression. The MAX9777/MAX9778 are stereo BTL/headphone amplifiers. The MAX9777 is controlled through an I²C-compatible, 2-wire serial interface. The MAX9778 is controlled through five logic inputs: MUTE, SHDN, HPS_EN, GAINA/B, and IN1/2 (see the *Selector Guide*). The MAX9777/MAX9778 feature exceptional PSRR (100dB at 1kHz), allowing these devices to operate from noisy digital supplies without the need for a linear regulator.

The speaker amplifiers use a BTL configuration. The signal path is composed of an input amplifier and an output amplifier. Resistor R_{IN} sets the input amplifier's gain, and resistor R_F sets the output amplifier's gain. The output of these two amplifiers serves as the input to a slave amplifier configured as an inverting unity-gain follower. This results in two outputs, identical in magnitude, but 180° out of phase. The overall gain of the speaker amplifiers is twice the product of the two amplifier gains (see the *Gain-Setting Resistors* section). A feature of this architecture is that there is no phase inversion from input to output.

When configured as a headphone (single-ended) amplifier, the slave amplifier is disabled, muting the speaker and the main amplifier drives the headphone. The MAX9777/MAX9778 can deliver 3W of continuous power into a 3 Ω load with less than 1% THD+N in speaker mode, and 200mW of continuous average power into a 16 Ω load with less than 1% THD+N in headphone mode. These devices also feature thermal-overload protection.

BIAS

These devices operate from a single 5V supply, and feature an internally generated, power-supply independent, common-mode bias voltage of 2.5V referenced to GND. BIAS provides both click-and-pop suppression and sets the DC bias level for the audio outputs. BIAS is internally connected to the noninverting input of each speaker amplifier (see the *Typical Application Circuits* and *Functional Diagrams*). Choose the value of the bypass capacitor as described in the *BIAS Capacitor* section. No external load should be applied to BIAS. Any load lowers the BIAS voltage, affecting the overall performance of the device.

Input Multiplexer

Each amplifier features a 2:1 input multiplexer, allowing input selection between two stereo sources. Both multiplexers are controlled by bit 1 in the control register (MAX9777) or by the IN1/2 pin (MAX9778). A logic-low selects input IN_1 and a logic-high selects input IN_2.

The input multiplexer can also be used to further expand the number of gain options available from the MAX9777/MAX9778 family. Connecting the audio source to the device through two different input resistors (Figure 1) increases the number of gain options from two to four. Additionally, the input multiplexer allows a speaker equalization network to be switched into the speaker signal path. This is typically useful in optimizing acoustic response from speakers with small physical dimensions.

Headphone Sense Enable

The HPS input is enabled by HPS_EN (MAX9778) or the HPS_D bit (MAX9777). HPS_D or HPS_EN determines whether the device is in automatic detection mode or fixed-mode operation (see Tables 1a and 1b).

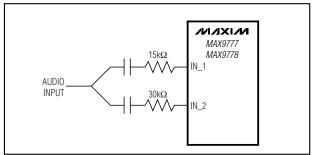


Figure 1. Using the Input Multiplexer for Gain Setting

Table 1a. MAX9777 HPS Setting

	INPUTS		0.4.11	
HPS_D BIT	HPS	SPKR/HP BIT	MODE	GAIN PATH*
0	0	Х	BTL	А
0	1	Х	SE	В
1	Х	0	BTL	A or B
1	Х	1	SE	A or B

*Note:

A—GAINA path selected

B—GAINB path selected

A or B—Gain path selected by GAINAB control bit in register 02h



Table 1b. MAX9778 HPS Setting

INP	UTS	MODE	GAIN PATH*
HPS_EN	HPS	WODE	GAIN PATH
0	Х	BTL	A or B
1	0	BTL	A or B
1	1	SE	A or B

*Note:

A or B-Gain path selected by external GAINAB

Headphone Sense Input (HPS)

With headphone sense enabled, a voltage on HPS less than $0.7 \times V_{DD}$ sets the device to speaker mode. A voltage greater than $0.9 \times V_{DD}$ disables the inverting bridge amplifier (OUT_-), which mutes the speaker amplifier and sets the device into headphone mode.

For automatic headphone detection, enable headphone sense and connect HPS to the control pin of a 3-wire headphone jack as shown in Figure 2. With no headphone present, the resistive voltage-divider created by R1 and R2 sets the voltage on HPS to be less than 0.7 x V_{DD}, setting the device to speaker mode and the gain setting defaults to GAINA (MAX9777). When a headphone plug is inserted into the jack, the control pin is disconnected from the tip contact, and HPS is pulled to V_{DD} through R1, setting the device into headphone mode and the gain-setting defaults to GAINB (MAX9777) (see the *Gain Select* section). Place a resistor in series with the control pin and HPS (R3) to prevent any audio signal from coupling into HPS when the device is in speaker mode.

Shutdown

The MAX9777/MAX9778 feature a 10μ A, low-power shutdown mode that reduces quiescent current consumption and extends battery life. The drive amplifiers and bias circuitry are disabled, the amplifier outputs (OUT_) go high impedance, and BIAS is driven to GND. Driving SHDN low places the devices into shutdown mode, disables the interface, and resets the l^2C registers to a default state. A logic-high on SHDN enables the devices.

MAX9777 Software Shutdown

A logic-high on bit 0 of the SHDN register places the MAX9777 in shutdown mode. A logic-low enables the

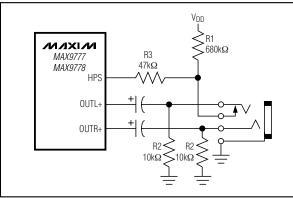


Figure 2. HPS Configuration Circuit

device. The digital section of the MAX9777 remains active when the device is shut down through the interface. All devices feature a logic-low on the SHDN input.

MUTE

The MAX9777/MAX9778 feature a mute mode. When the device is muted, the input is disconnected from the amplifiers. MUTE does not shut down the device.

MAX9777 MUTE

The MAX9777 MUTE mode is selected by writing to the MUTE register (see the *Mute Register* section). The left and right channels can be independently muted.

MAX9778 MUTE

The MAX9778 features an active-high MUTE input that mutes all channels.

Click-and-Pop Suppression

The MAX9777/MAX9778 feature Maxim's patented comprehensive click-and-pop suppression. When entering or exiting shutdown, the common-mode bias voltage of the amplifiers is slowly ramped to and from the DC bias point using an S-shaped waveform. In headphone mode, this waveform shapes the frequency spectrum, minimizing the amount of audible components present at the headphone. In speaker mode, the BTL amplifiers start up in the same fashion as in headphone mode. When entering shutdown, both amplifier outputs ramp to GND quickly and simultaneously. To maximize clickand-pop suppression, drive SHDN to 0V before powerup or power-down transitions.

Digital Interface

The MAX9777 features an I²C/SMBus[™]-compatible 2wire serial interface consisting of a serial data line (SDA) and a serial clock line (SCL). SDA and SCL facilitate bidirectional communication between the MAX9777 and the master at clock rates up to 400kHz. Figure 3 shows the 2-wire interface timing diagram. The MAX9777 is a transmit/receive slave-only device, relying upon a master to generate a clock signal. The master (typically a microcontroller) initiates data transfer on the bus and generates SCL to permit that transfer.

A master device communicates to the MAX9777 by transmitting the proper address followed by a command and/or data words. Each transmit sequence is framed by a START (S) or REPEATED START (S_r) condition and a STOP (P) condition. Each word transmitted over the bus is 8 bits long and is always followed by an acknowledge clock pulse.

SDA and SCL are open-drain outputs requiring a pullup resistor (500Ω or greater) to generate a logic-high voltage. Series resistors in line with SDA and SCL are optional. These series resistors protect the input stages of the

SMBus is a trademark of Intel Corp.

devices from high-voltage spikes on the bus lines, and minimize crosstalk and undershoot of the bus signals.

Bit Transfer

One data bit is transferred during each SCL clock cycle. The data on SDA must remain stable during the high period of the SCL clock pulse. Changes in SDA while SCL is high are control signals (see the *START* and *STOP Conditions* section). SDA and SCL idle high when the l²C bus is not busy.

START and STOP Conditions

When the serial interface is inactive, SDA and SCL idle high. A master device initiates communication by issuing a START condition. A START condition is a high-tolow transition on SDA with SCL high. A STOP condition is a low-to-high transition on SDA while SCL is high (Figure 4). A START condition from the master signals the beginning of a transmission to the MAX9777. The master terminates transmission by issuing the STOP condition; this frees the bus. If a REPEATED START condition is generated instead of a STOP condition, the bus remains active.

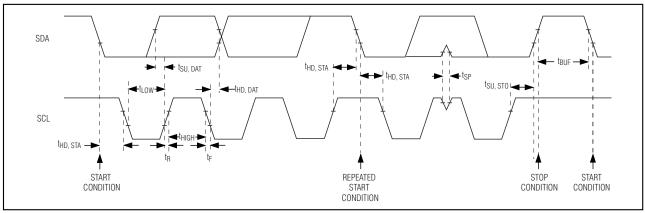


Figure 3. 2-Wire Serial-Interface Timing Diagram

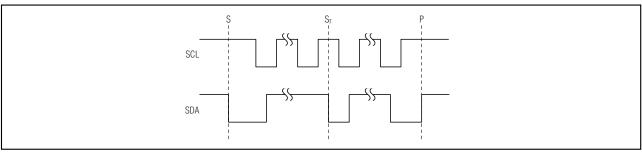


Figure 4. START/STOP Conditions

///XI///

Early STOP Conditions

The MAX9777 recognizes a STOP condition at any point during the transmission except if a STOP condition occurs in the same high pulse as a START condition (Figure 5). This condition is not a legal I²C format; at least one clock pulse must separate any START and STOP condition.

REPEATED START Conditions

A REPEATED START (S_r) condition may indicate a change of data direction on the bus. Such a change occurs when a command word is required to initiate a read operation. S_r may also be used when the bus master is writing to several I²C devices and does not want to relinquish control of the bus. The MAX9777 serial interface supports continuous write operations with or without an S_r condition separating them. Continuous read operations require S_r conditions because of the change in direction of data flow.

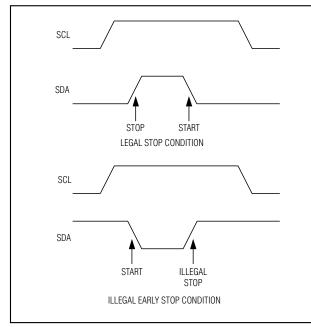


Figure 5. Early STOP Condition

Acknowledge Bit (ACK)

The acknowledge bit (ACK) is the ninth bit attached to any 8-bit data word. The receiving device always generates ACK. The MAX9777 generates an ACK when receiving an address or data by pulling SDA low during the night clock period. When transmitting data, the MAX9777 waits for the receiving device to generate an ACK. Monitoring ACK allows for detection of unsuccessful data transfers. An unsuccessful data transfer occurs if a receiving device is busy or if a system fault has occurred. In the event of an unsuccessful data transfer, the bus master should reattempt communication at a later time.

Slave Address

The bus master initiates communication with a slave device by issuing a START condition followed by a 7-bit slave address (Figure 6). When idle, the MAX9777 waits for a START condition followed by its slave address. The LSB of the address word is the Read/Write (R/W) bit. R/W indicates whether the master is writing to or reading from the MAX9777 (R/W = 0 selects the write condition, R/W = 1 selects the read condition). After receiving the proper address, the MAX9777 issues an ACK by pulling SDA low for one clock cycle.

The MAX9777 has a factory-/user-programmed address. Address bits A6–A2 are preset, while A0 and A1 is set by ADD. Connect ADD to either V_{DD} , GND, SCL, or SDA to change the last 2 bits of the slave address (Table 2).

	-					-		
S	A6	A5	A4	A3	A2	A1	A0	R/W

Figure 6. Slave Address Byte Definition

Table 2. MAX9777 I²C Slave Addresses

ADD CONNECTION	I ² C ADDRESS
GND	100 1000
V _{DD}	100 1001
SDA	100 1010
SCL	100 1011

MAX9777/MAX9778

Write Data Format

There are three registers that configure the MAX9777: the MUTE register, SHDN register, and control register. In write data mode (R/W = 0), the register address and data byte follow the device address (Figure 7).

MUTE Register

The MUTE register (01hex) is a read/write register that sets the MUTE status of the device. Bit 3 (MUTEL) of the MUTE register controls the left channel; bit 4 (MUTER) controls the right channel. A logic-high mutes the respective channel; a logic-low brings the channel out of mute.

SHDN Register

The SHDN register (02hex) is a read/write register that controls the power-up state of the device. A logic-high

in bit 0 of the SHDN register shuts down the device; a logic-low turns on the device. A logic-high is required in bits 2 to 7 to reset all registers to their default settings.

Control Register

The control register (03hex) is a read/write register that determines the device configuration. Bit 1 (IN1/IN2) controls the input multiplexer, a logic-high selects input 1; a logic-low selects input 2. Bit 2 (HPS_D) controls the headphone sensing. A logic-low configures the device in automatic headphone detection mode. A logic-high disables the HPS input. Bit 3 (GAINA/B) controls the gain-select multiplexer. A logic-low selects GAINA. A logic-high selects GAINB. GAINA/B is ignored when HPS_D = 0. Bit 4 (SPKR/HP) selects the amplifier operating mode when HPS_D = 1. A logic-high selects speaker mode, and a logic-low selects headphone mode.

S	ADDRESS	WR	ACK	COMMAND	ACK	DAT	A ACK	Р			
	7 BITS			8 BITS		8 BIT	TS	1			
	I ² C SLAVE ADD SELECTS DE\			REGISTER ADDRI SELECTS REGISTER WRITTEN TO	TO BE	RE	EGISTER DA	A			
S	ADDRESS	WR	ACK	COMMAND	ACK	S	ADDRESS	WB	ACK	ΠΔΤΔ	P
S	ADDRESS 7 BITS	WR	ACK	COMMAND 8 BITS	ACK	S	ADDRESS 7 BITS	WR	ACK	DATA 8 BITS	P 1

Figure 7. Write/Read Data Format Example

Table 3. MAX9777 MUTE Register Format

ISTER RESS	(0000 0001
NAME	VALUE	DESCRIPTION
Х	Don't Care	—
Х	Don't Care	_
Х	Don't Care	—
	0*	Unmute right channel
NUTER	1	Mute right channel
	0*	Unmute left channel
WUTEL	1	Mute left channel
Х	Don't Care	_
Х	Don't Care	_
Х	Don't Care	—
	RESS NAME X X X MUTER MUTEL X X	RESSNAMEVALUEXDon't CareXDon't CareXDon't CareMUTER0*MUTEL0*10*XDon't CareXDon't CareXDon't CareXDon't CareXDon't CareXDon't CareXDon't CareXDon't Care

*Default state.

Table 4. MAX9777 SHDN Register Format

REGIST	ER ADDRESS	00	000 0010
BIT	NAME	VALUE	DESCRIPTION
7	RESET	0*	—
	NESEI	1	Reset device
6	RESET	0*	—
0	NLOLI	1	Reset device
5	RESET	0*	—
5	NESEI	1	Reset device
4	RESET	0*	—
4	NESEI	1	Reset device
3	RESET	0*	—
3	NESEI	1	Reset device
2	RESET	0*	—
2	RESEI	1	Reset device
1	Х	Don't Care	_
0	SHDN	0*	Normal operation
	SUDIN	1	Shutdown

*Default state.

REGISTE	R ADDRESS		0000 0011
BIT	NAME	VALUE	DESCRIPTION
7	Х	Don't Care	—
6	Х	Don't Care	—
5	Х	Don't Care	—
		0*	Speaker mode selected
4	SPKR/HP	1	Headphone mode selected
3		0*	Gain-setting A selected
3	GAINA/B	1	Gain-setting B selected
		0*	Automatic headphone detection enabled
2	HPS_D	1	Automatic headphone detection disabled (HPS ignored)
1	IN1/IN2	0*	Input 1 selected
		1	Input 2 selected
0	Х	Don't Care	

Table 5. MAX9777 Control Register Format

Read Data Format

In read mode (R/W = 1), the MAX9777 writes the contents of the selected register to the bus. The direction of the data flow reverses following the address acknowledge by the MAX9777. The master device reads the contents of all registers, including the read-only status register. Table 6 shows the status register format.

Interrupt Output (INT)

The MAX9777 includes an interrupt output (INT) that can indicate to a master device that an event has occurred. INT is triggered when the state of HPS changes. During normal operation, INT idles high. If a headphone is inserted/removed from the jack and that action is detected by HPS, INT pulls the line low. INT remains low until a read data operation is executed.

I²C Compatibility

The MAX9777 is compatible with existing I²C systems. SCL and SDA are high-impedance inputs; SDA has an open drain that pulls the data line low during the ninth clock pulse. The communication protocol supports the standard I²C 8-bit communications. The general call address is ignored. The MAX9777 slave addresses are compatible with the 7-bit I²C addressing protocol only.

*Default

Table 6. MAX9777 Status Register Format

REGI	STER ADDRESS		0000 0000
BIT	NAME	VALUE	DESCRIPTION
7	THRM	0	Device temperature below thermal limit
/		1	Device temperature exceeding thermal limit
6	AMPR-	0	OUTR- current below current limit
0	AIVIPR-	1	OUTR- current exceeding current limit
		0	OUTR+ current below current limit
5	AMPR+	1	OUTR+ current exceeding current limit
4	AMPL-	0	OUTL- current below current limit
4	AIVIPL-	1	OUTL- current exceeding current limit
0	AMPL+	0	OUTL+ current below current limit
3	AIVIPL+	1	OUTL+ current exceeding current limit
2	HPSTS	0	Device in speaker mode
2	nr313	1	Device in headphone mode
1	Х	Don't Care	_
0	Х	Don't Care	—

Applications Information

BTL Speaker Amplifiers

The MAX9777/MAX9778 feature speaker amplifiers designed to drive a load differentially, a configuration referred to as bridge-tied load (BTL). The BTL configuration (Figure 8) offers advantages over the singleended configuration, where one side of the load is connected to ground. Driving the load differentially doubles the output voltage compared to a singleended amplifier under similar conditions. Thus, the devices' differential gain is twice the closed-loop gain of the input amplifier. The effective gain is given by:

$$A_{VD} = 2 \times \frac{R_F}{R_{IN}}$$

Substituting 2 x $V_{OUT(P-P)}$ for $V_{OUT(P-P)}$ into the following equations yields four times the output power due to doubling of the output voltage:

$$V_{RMS} = \frac{V_{OUT(P-P)}}{2\sqrt{2}}$$
$$P_{OUT} = \frac{V_{RMS}^{2}}{R_{L}}$$

Since the differential outputs are biased at midsupply, there is no net DC voltage across the load. This eliminates the need for DC-blocking capacitors required for single-ended amplifiers. These capacitors can be large and expensive, consume board space, and degrade low-frequency performance.

When the MAX9777 is configured to automatically detect the presence of a headphone jack, the device defaults to gain setting A when the device is in speaker mode.

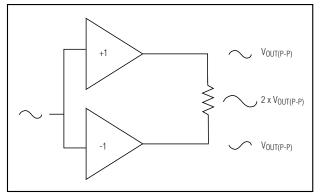


Figure 8. Bridge-Tied Load Configuration

Single-Ended Headphone Amplifier

The MAX9777/MAX9778 can be configured as singleended headphone amplifiers through software or by sensing the presence of a headphone plug (HPS). In headphone mode, the inverting output of the BTL amplifier is disabled, muting the speaker. The gain is 1/2 that of the device in speaker mode, and the output power is reduced by a factor of 4.

In headphone mode, the load must be capacitively coupled to the device, blocking the DC bias voltage from the load (see the *Typical Application Circuits*).

Power Dissipation and Heat Sinking

Under normal operating conditions, the MAX9777/ MAX9778 can dissipate a significant amount of power. The maximum power dissipation for each package is given in the *Absolute Maximum Ratings* section under Continuous Power Dissipation or can be calculated by the following equation:

$$P_{\text{DISSPKG}(\text{MAX})} = \frac{T_{\text{J}(\text{MAX})} - T_{\text{A}}}{\theta_{\text{JA}}}$$

where $T_{J(MAX)}$ is +150°C, T_A is the ambient temperature, and θ_{JA} is the reciprocal of the derating factor in °C/W as specified in the *Absolute Maximum Ratings* section. For example, θ_{JA} of the TQFN package is +29°C/W.

The increase in power delivered by the BTL configuration directly results in an increase in internal power dissipation over the single-ended configuration. The maximum power dissipation for a given V_{DD} and load is given by the following equation:

$$P_{\text{DISS}(\text{MAX})} = \frac{2V_{\text{DD}}^2}{\pi^2 R_{\text{I}}}$$

If the power dissipation for a given application exceeds the maximum allowed for a given package, either reduce V_{DD}, increase load impedance, decrease the ambient temperature, or add heatsinking to the device. Large output, supply, and ground PC board traces improve the maximum power dissipation in the package.

Thermal-overload protection limits total power dissipation in these devices. When the junction temperature exceeds +160°C, the thermal-protection circuitry disables the amplifier output stage. The amplifiers are enabled once the junction temperature cools by 15°C. This results in a pulsing output under continuous thermal-overload conditions as the device heats and cools.

/VI/IXI/VI

Component Selection Gain-Setting Resistors

External feedback components set the gain of the MAX9777/MAX9778. Resistor R_{IN} sets the gain of the input amplifier (A_{VIN}), and resistor R_F sets the gain of the second stage amplifier (A_{VOUT}):

$$A_{VIN} = -\left(\frac{10k\Omega}{R_{IN}}\right), \ A_{VOUT} = -\left(\frac{R_F}{10k\Omega}\right)$$

Combining AVIN and AVOUT, RIN and RF set the singleended gain of the device as follows:

$$A_{V} = A_{VIN} \times A_{VOUT} = -\left(\frac{10k\Omega}{R_{IN}}\right) \times -\left(\frac{R_{F}}{10k\Omega}\right) = +\left(\frac{R_{F}}{R_{IN}}\right)$$

As shown, the two-stage amplifier architecture results in a noninverting gain configuration, preserving absolute phase through the MAX9777/MAX9778. The gain of the device in BTL mode is twice that of the single-ended mode. Choose R_{IN} between 10k Ω and 15k Ω and R_F between 15k Ω and 100k Ω .

Input Filter

The input capacitor (C_{IN}), in conjunction with R_{IN} , forms a highpass filter that removes the DC bias from an incoming signal. The AC-coupling capacitor allows the amplifier to bias the signal to an optimum DC level. Assuming zero-source impedance, the -3dB point of the highpass filter is given by:

$$f_{-3dB} = \frac{1}{2\pi R_{IN} C_{IN}}$$

Choose R_{IN} according to the *Gain-Setting Resistors* section. Choose the C_{IN} such that f_{-3dB} is well below the lowest frequency of interest. Setting f_{-3dB} too high affects the amplifier's low-frequency response. Use capacitors whose dielectrics have low-voltage coefficients, such as tantalum or aluminum electrolytic. Capacitors with high-voltage coefficients, such as ceramics, may result in an increased distortion at low frequencies.

Other considerations when designing the input filter include the constraints of the overall system, the actual frequency band of interest, and click-andpop suppression.

Output-Coupling Capacitor

The MAX9777/MAX9778 require output-coupling capacitors to operate in single-ended (headphone) mode. The output-coupling capacitor blocks the DC component of the amplifier output, preventing DC current from flowing to the load. The output capacitor and

M/X/M

the load impedance form a highpass filter with a -3dB point determined by:

$$f_{-3dB} = \frac{1}{2\pi R_L C_{OUT}}$$

As with the input capacitor, choose C_{OUT} such that f_{-3dB} is well below the lowest frequency of interest. Setting f_{-3dB} too high affects the amplifier's low-frequency response.

Load impedance is a concern when choosing C_{OUT}. Load impedance can vary, changing the -3dB point of the output filter. A lower impedance increases the corner frequency, degrading low-frequency response. Select C_{OUT} such that the worst-case load/C_{OUT} combination yields an adequate response. Select capacitors with low ESR to minimize resistive losses and optimize power transfer to the load.

If layout constraints require a physically smaller outputcoupling capacitor, decrease the value of C_{OUT} and add series resistance to the output of the MAX9777/MAX9778 (see Figure 9). With the added series resistance at the output, the cutoff frequency of the highpass filter is:

$$f_{-3dB} = \frac{1}{2\pi (R_L + R_{SERIES})C_{OUT}}$$

1

Since the cutoff frequency of the output highpass filter is inversely proportional to the product of the total load resistance seen by the outputs (R_L + RSERIES) and COUT, increase the total resistance seen by the MAX9777/MAX9778 outputs by the same amount COUT is decreased to maintain low-frequency performance. Since the added series resistance forms a voltagedivider with the headphone speaker resistance for frequencies within the passband of the highpass filter, there is a loss in voltage gain. To compensate for this loss, increase the voltage gain setting by an amount equal to the attenuation due to the added series resistance. Use the following equation to approximate the required voltage gain compensation:

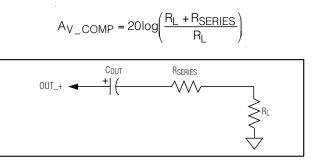


Figure 9. Reducing COUT by Adding RSERIES

BIAS Capacitor

BIAS is the output of the internally generated 2.5VDC bias voltage. The BIAS bypass capacitor, C_{BIAS}, improves PSRR and THD+N by reducing power supply and other noise sources at the common-mode bias node, and also generates the clickless/popless, start-up/shutdown DC bias waveforms for the speaker amplifiers. Bypass BIAS with a 1 μ F capacitor to GND.

Supply Bypassing

Proper power-supply bypassing ensures low-noise, lowdistortion performance. Place a 0.1μ F ceramic capacitor from V_{DD} to GND. Add additional bulk capacitance as required by the application, typically 100 μ F. Bypass PV_{DD} with a 100 μ F capacitor to GND. Locate bypass capacitors as close to the device as possible.

Gain Select

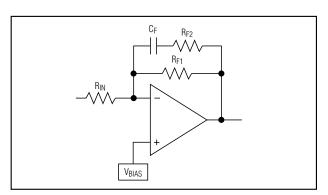
The MAX9777/MAX9778 feature multiple gain settings on each channel, making available different gain and feedback configurations. The gain-setting resistor (R_F) is connected between the amplifier output (OUT_+) and the gain set point (GAIN_). An internal multiplexer switches between the different feedback resistors depending on the status of the gain control input. The stereo MAX9777/MAX9778 feature two gain options per channel. See Tables 1a and 1b for the gain-setting options.

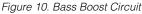
Bass Boost Circuit

Headphones typically have a poor low-frequency response due to speaker and enclosure size limitations. A bass boost circuit compensates the poor low-frequency response (Figure 10). At low frequencies, the capacitor CF is an open circuit, and the effective impedance in the feedback loop (RF(EFF)) is RF(EFF) = RF1.

At the frequency:







where the impedance, CF, begins to decrease, and at high frequencies, the CF is a short circuit. Here the impedance of the feedback loop is:

$$R_{F(EFF)} = \frac{R_{F1} \times R_{F2}}{R_{F1} + R_{F2}}$$

Assuming $R_{F1} = R_{F2}$, then $R_{F(EFF)}$ at low frequencies is twice that of $R_{F(EFF)}$ at high frequencies (Figure 11). Thus, the amplifier has more gain at lower frequencies, boosting the system's bass response. Set the gain rolloff frequency based upon the response of the speaker and enclosure.

To minimize distortion at low frequencies, use capacitors with low-voltage coefficient dielectrics when selecting CF. Film or COG dielectric capacitors are good choices for CF. Capacitors with high-voltage coefficients, such as ceramics (non-COG dielectrics), can result in increased distortion at low frequencies.

Layout and Grounding

Good PC board layout is essential for optimizing performance. Use large traces for the power-supply inputs and amplifier outputs to minimize losses due to parasitic trace resistance, as well as route heat away from the device. Good grounding improves audio performance, minimizes crosstalk between channels, and prevents any digital switching noise from coupling into the audio signal. If digital signal lines must cross over or under audio signal lines, ensure that they cross perpendicular to each other.

The MAX9777/MAX9778 TQFN package features an exposed thermal pad. This pad lowers the package's thermal resistance by providing a direct heat conduction path from the die to the PC board. Connect the pad to signal ground (0V) by using a large pad or multiple vias to the ground plane.

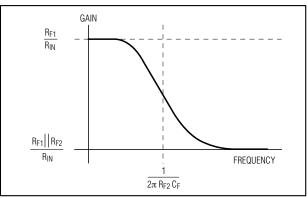
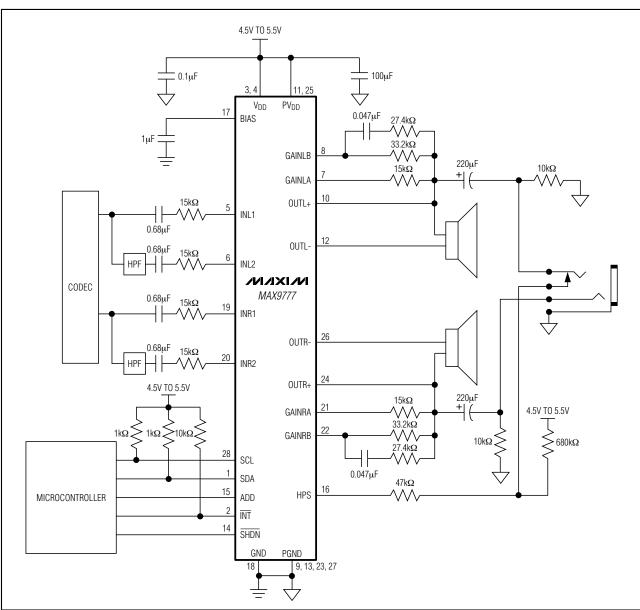
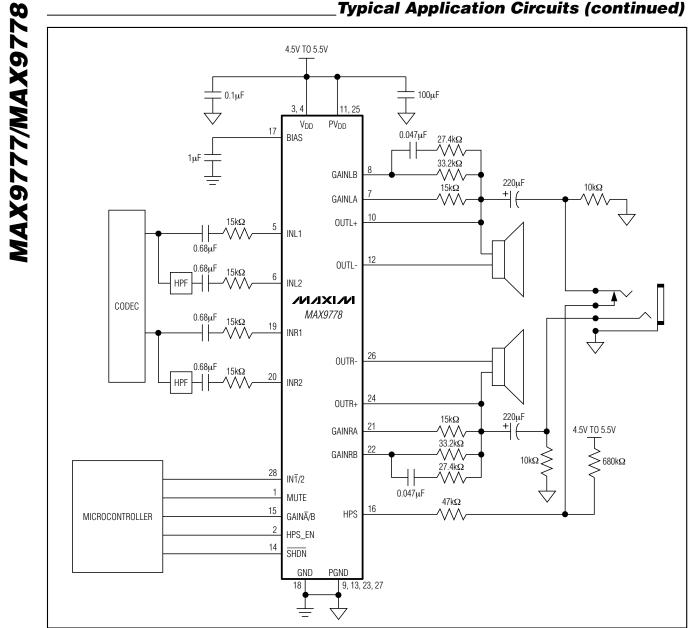


Figure 11. Bass Boost Response

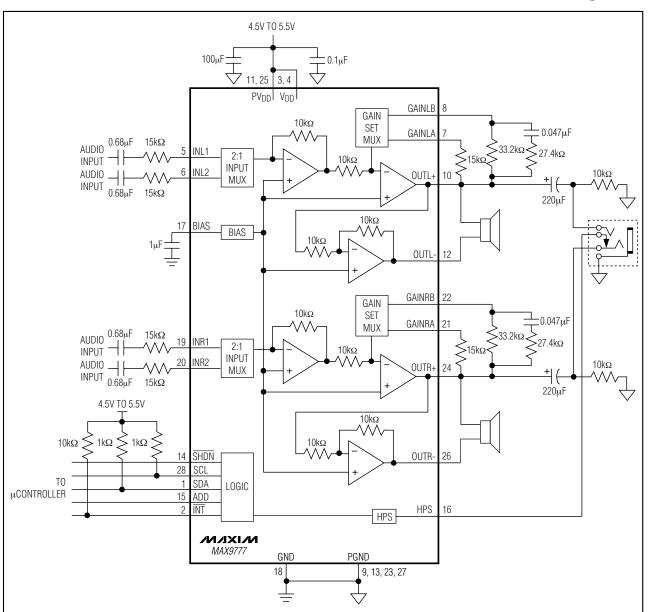




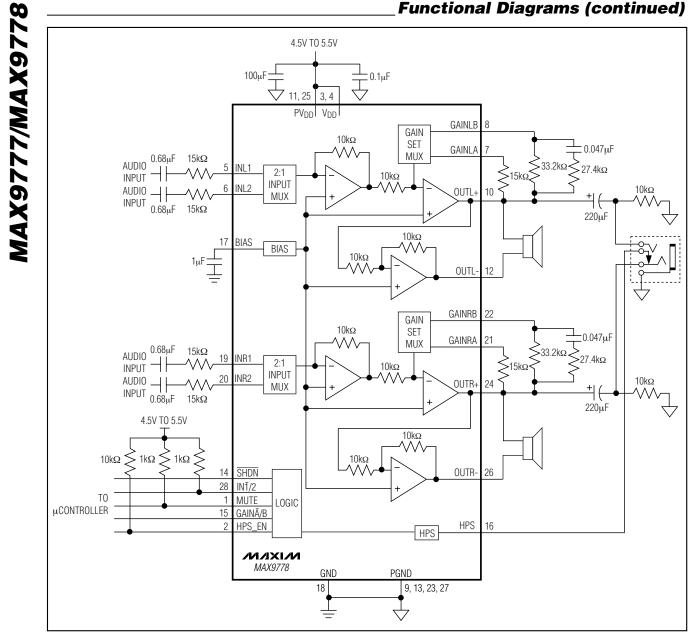


Typical Application Circuits (continued)

_Functional Diagrams



Functional Diagrams (continued)



24

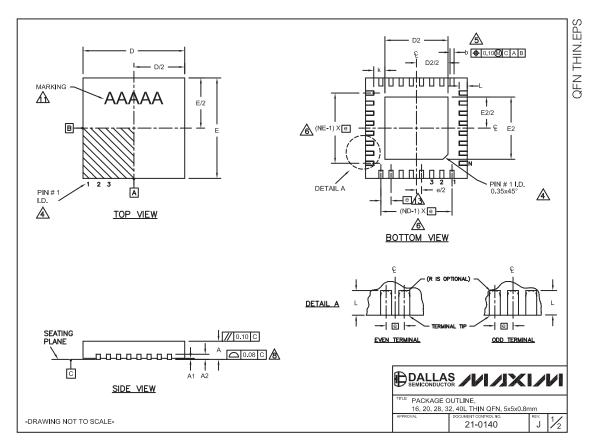
TOP VIEW TOP VIEW GAINĀ/B GAINRA GAINRA INR2 INR2 GND BIAS GND BIAS HPS INR1 ADD INR1 21 20 19 18 17 16 15 21 20 19 18 17 16 15 GAINRB 22 14 SHDN GAINRB 22 14 SHDN PGND [13 PGND 13 PGND PGND 23 23 12 OUTL-OUTR+ 24 12 OUTL-OUTR+ 24 MIXI/M /VI/IXI/VI [11 $\mathsf{PV}_{\mathsf{DD}}$ 11 PV_DD PV_{DD} 25 PVDD 25 MAX9777 MAX9778 OUTR-10 OUTR-26 10 OUTL+ 26 OUTL+ 27 27 PGND PGND 9 PGND PGND 9 8 28 8 GAINLB INT/2 28 GAINLB SCL 1 2 3 4 5 6 7 4 5 6 7 1 2 3 ! ! GAINLA MUTE GAINLA HPS_EN INL1 INL2 ۵۵۸ VDD INL1 INL2 SDA INT VDD VDD THIN QFN THIN QFN

_Pin Configurations

MAX9777/MAX9778

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to <u>www.maxim-ic.com/packages</u>.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to <u>www.maxim-ic.com/packages</u>.)

			С	OMM	DN DI	MENS	SIONS	;										EXI	POSEI	D PAD	VARI		١S	
PKG.		6L 5x			0L 5x			3L 5x			32L 5			40L 5		ŀ	PKG.		D2			E2		
SYMBOL	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM	. MAX	MIN.	NOM.	MAX.		CODES	MIN.	NOM.	MAX.	MIN.	NOM	. MAX	
А	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	ŀ	T1655-2	3.00	3.10	3.20	3.00	3.10	3.20	,
A1	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	ŀ	T1655-3	3.00	3.10	3.20	3.00	3.10	3.20)
A2	0.	.20 RE	F.	0.	20 RE	F.	0.2	20 RE	F.	0.	20 R	EF.	0	.20 RE	EF.	ŀ	T1655N-1	3.00		3.20	3.00	3.10	3.20)
b		0.30														ľ	T2055-3	3.00	3.10	3.20	3.00	3.10	3.20)
D	_	5.00		_					_		_		_			ŀ	T2055-4	3.00	3 10	3.20	3.00	3.10	3.20	2
E						-	4.90						_	5.00	_	ŀ	T2055-5	3.15	3.25				3.35	
е		.80 BS			.65 BS			50 BS			.50 E	1	-).40 B	sc.	ŀ	T2855-3	3.15			3.15	3.25	3.35	_
k	0.25			0.25	-		0.25	-		0.25	-	-	0.25		-	ŀ	T2855-4	2.60	2.70	2.80	2.60	2.70	2.80	
L	0.30	_	0.50	0.45	_	0.65	0.45	-	0.65	0.30	-	0.50	0.30	0.40	0.50	ŀ	T2855-5	2.60	2.70				2.80	_
N ND	-	16 4			20 5			28 7			32 8			40		ŀ	T2855-6	3.15	3.25	3.35	3.15		3.35	
NE	-	4			5			7			8		-	10		ŀ	T2855-7	2.60		2.80	2.60		2.80	_
JEDEC	+	WHHE	3	1	NHHC		W	, /HHD	-1	V	VHH	D - 2	-			ŀ	T2855-8	3.15	3.25		3.15	<u> </u>	3.35	-
																ŀ	T2855N-1	3.15	3.25	3.35	3.15		3.35	
OTES:																	T3255-3 T3255-4	3.00		3.20	3.00	3.10	3.20)
IOTES: 1. DIM 2. ALL 3. NIS	DIME	NSIO	NS AF	REINI	MILLIN	METER	RS. AN									-	T3255-4 T3255-5 T3255N-1 T4055-1	3.00 3.00 3.00 3.40	3.10 3.10 3.10 3.50	3.20 3.20 3.20 3.60	3.00 3.00 3.00 3.40	3.10 3.10 3.10 3.50	3.20 3.20 3.20 3.60	
1. DIM 2. ALL 3. N IS A THE COI OP IDE	DIME S THE E TERI NFORI TIONA NTIFIE	ENSIO TOTA MINAL M TO L, BU ER MA	NS AF L NUM JESD T MUS Y BE	RE IN I MBER DENTII 95-1 3 95-1 3 95-	MILLIN OF TE FIER / SPP-0 LOCA ER A N	METER ERMIN AND T 12. D 12. D 14. D	RS. AN IALS. ERMII ETAIL WITHI OR M ED TE	IGLE NAL I S OF N THI ARKE	S ARE NUMB TERM E ZOM ED FE	E IN C ERIN MINAL JE INI ATUF	G CC _ #1 I DICA RE.	EES. NVEN DENT TED.	IFIER THE T	ARE ERM I I	NAL #1		T3255-4 T3255-5 T3255N-1	3.00 3.00 3.00 3.40 3.40	3.10 3.10 3.10 3.50 3.50	3.20 3.20 3.20 3.60 3.60	3.00 3.00 3.00	3.10 3.10 3.10 3.50 3.50	3.20 3.20 3.20 3.60 3.60	
1. DIM 2. ALL 3. N IS A THE COI OP IDE	DIME S THE E TERI NFORI TIONA NTIFIE MENSIO 5 mm /	ENSIO TOTA MINAL M TO L, BU ER MA ON b A AND 0	NS AF L NUM JESD T MUS Y BE APPLIE	RE IN I MBER 95-1 95-1 95-1 BT BE EITHE ES TC m FR(MILLIN OF TE FIER / SPP-0 LOCA ER A N MET. DM TE	METER ERMIN 12. D ATED V MOLD ALLIZI ERMIN	RS. AN IALS. ERMII ETAIL WITHI OR M ED TE AL TIF	IGLE S OF N THI ARKE	S ARE TERM E ZON ED FE IAL AI	E IN C ERIN MINAL JE INI ATUF ND IS	G CC _ #1 I DICA RE. ; MEA	EES. INVEN DENT TED. SURE	IFIER THE T	ARE ERMII TWEE	NAL #1		T3255-4 T3255-5 T3255N-1 T4055-1 T4055-2	3.00 3.00 3.00 3.40 3.40	3.10 3.10 3.10 3.50 3.50	3.20 3.20 3.20 3.60 3.60	3.00 3.00 3.00 3.40 3.40	3.10 3.10 3.10 3.50 3.50	3.20 3.20 3.20 3.60 3.60	
1. DIM 2. ALL 3. N IS COI OPT IDE 0.25	DIME S THE E TERI NFORI TIONA ENTIFIE MENSIO 5 mm /	ENSION TOTA MINAL M TO L, BU ER MA ON b A AND 0 NE RE	NS AF L NUM JESD T MUS Y BE APPLIE J30 mi	RE IN I MBER DENTII 95-1 (95-1 (95-1))))))))))))))))))))))))))))))))))))	MILLIN OF TE FIER / SPP-0 LOCA ER A N MET. DM TE E NUT	METER ERMIN AND T 12. D 12. D	RS. AN IALS. ERMIT ETAIL WITHI OR M ED TE AL TIF OF TE	NAL N S OF N THI ARKE RMIN P. ERMIN	S ARE TERI E ZON ED FE IAL AI	E IN C ERIN MINAL VE INI ATUF ND IS ON E	G CC _ #1 I DICA RE. 5 MEA	EES. INVEN DENT TED. SURE	IFIER THE T	ARE ERMII TWEE	NAL #1		T3255-4 T3255-5 T3255N-1 T4055-1 T4055-2	3.00 3.00 3.00 3.40 3.40	3.10 3.10 3.10 3.50 3.50	3.20 3.20 3.20 3.60 3.60	3.00 3.00 3.00 3.40 3.40	3.10 3.10 3.10 3.50 3.50	3.20 3.20 3.20 3.60 3.60	
1. DIM 2. ALL 3. N IS A THE COI OPT IDE DIM 0.25 A ND	DIME S THE E TERI NFORI TIONA NTIFIE MENSIC 5 mm / AND N POPUI	ENSION TOTA MINAL M TO AL, BU ER MA ON 6 A AND 0 NE RE LATIO	NS AR L NUM JESD T MUS Y BE APPLIE .30 m FER T	RE IN I MBER DENTII 95-1 ST BE EITHE ES TO THE FO TH POSSI	MILLIN OF TE FIER / SPP-0 LOCA ER A N MET. DM TE E NUT BLE IT	METER ERMIN 12. D 12. D	RS. AN IALS. ERMIT ETAIL WITHI OR M ED TE AL TIF OF TE (MME)	NAL N S OF N THI ARKE RMIN ERMIN	S ARE TERME ZONE D FE IAL AI NALS AL FA	E IN C ERIN MINAL JE INI ATUF ND IS ON E SHIO	G CC #1 I DICA RE. MEA EACH	EES. DENT TED. SURE D AN	IFIER THE T D BE	ARE ERMII TWEE IDE RI	NAL #1 N ESPEC	TIVEL	T3255-4 T3255-5 T3255N-1 T4055-1 T4055-2	3.00 3.00 3.00 3.40 3.40	3.10 3.10 3.10 3.50 3.50	3.20 3.20 3.20 3.60 3.60	3.00 3.00 3.00 3.40 3.40	3.10 3.10 3.10 3.50 3.50	3.20 3.20 3.20 3.60 3.60	
1. DIM 2. ALL 3. N IS COI OP IDE DIM 0.25	DIME S THE E TERI NFORI TIONA NTIFIE AENSIG 5 mm / AND N POPUI PLANA	ENSION TOTA MINAL M TO (L, BU ER MA ON 6 A AND 0 NE RE LATIO ARITY G CON	NS AF L NUN JESD T MUS APPLIE 30 mi FER T N IS F APPL	RE IN I MBER DENTII 95-1 (37 BE EITHE ES TC m FRC FO TH POSSI .IES T MS TC	MILLIN OF TE FIER / SPP-0 LOCA ER A M D MET. D MET. D MET. D MET. D MET. D MET. D MET.	METER ERMIN 12. D ATED V MOLD ALLIZI RMIN MBER N A SY E EXP	RS. AN IALS. ERMIT ETAIL WITHI OR M ED TE AL TIF OF TE /MME [*] OSED	NAL N S OF N THI ARKE RMIN C ERMIN TRIC, HEA	S ARE TERME ZON E ZON E	E IN C ERIN MINAL NE INI ATUF ND IS ON E SHIO K SLU	G CC #1 I DICA RE. MEA EACH N. JG A	EES. INVEN DENT TED. SURE D AN	IFIER THE T ED BE D E S L AS	ARE ERMIN TWEE IDE RI THE T	NAL #1 N ESPEC	TIVEL	T3255-4 T3255-5 T3255N-1 T4055-1 T4055-2	3.00 3.00 3.00 3.40 3.40	3.10 3.10 3.10 3.50 3.50	3.20 3.20 3.20 3.60 3.60	3.00 3.00 3.00 3.40 3.40	3.10 3.10 3.10 3.50 3.50	3.20 3.20 3.20 3.60 3.60	
1. DIM 2. ALL 3. N IS 3. N IS 4. THE COI OP ⁻ IDE COI OP ⁻ IDE 0.28 ND 7. DEF ▲. COI 9. DR/ T28 A	DIME S THE E TERI NFORI TIONA NTIFIE MENSIO 5 mm / AND N POPUI	ENSION TOTA MINAL M TO L, BU ER MA ON 6 A AND 0 NE RE LATIO ARITY G CON	NS AF L NUM JESD T MUS APPLIE 30 mi FER T N IS F APPL IS FORM 2855-0	RE IN I MBER 95-1 (3T BE EITHE ES TC m FR(FO TH POSSI JES T MS TC 3.	VILLIN OF TE SPP-0 LOCA ER A N MET. DM TE E NUP BLE IN O THE JEDE	METEF ERMIN AND T 12. D ATED V MOLD ALLIZI RMIN MBER N A SY E EXP EC MC	RS. AN IALS. ERMIT ETAIL OR M ED TE AL TIF OF TE (MME OSED 0220, E	NAL N S OF N THI ARKE RMIN C ERMIN TRIC, HEA	S ARE TERME ZON E ZON E	E IN C ERIN MINAL NE INI ATUF ND IS ON E SHIO K SLU	G CC #1 I DICA RE. MEA EACH N. JG A	EES. INVEN DENT TED. SURE D AN	IFIER THE T ED BE D E S L AS	ARE ERMIN TWEE IDE RI THE T	NAL #1 N ESPEC	TIVEL	T3255-4 T3255-5 T3255N-1 T4055-1 T4055-2	3.00 3.00 3.40 3.40 *	3.10 3.10 3.50 3.50 *SEE C	3.20 3.20 3.60 3.60	3.00 3.00 3.40 3.40	3.10 3.10 3.50 3.50	3.20 3.20 3.60 3.60 TABLE	
1. DIM 2. ALL 3. N IS 3. N IS 4. THE COI OP ⁻ IDE COI OP ⁻ IDE 0.28 ND 7. DEF ▲. COI 9. DR/ T28 A	DIME S THE E TERI NFORI TIONA NTIFIE MENSIO 5 mm / AND M POPUI PLAN/ AWING 355-3 / RPAG	ENSION TOTA MINAL M TO L, BU ER MA ON 6 A AND 0 NE RE LATIO ARITY G CON AND T E SHA	NS AF L NUM JESD T MUS APPLIE APP	RE IN I MBER DENTII 95-1 95-1 ST BE EITHE ES TC M FRO TO TH POSSI IES T MS TC 3. DT EX	VILLIN OF TE FIER / SPP-0 LOCA ER A N MET. DM TE E NUT BLE IT O THE D JEDE	METER ERMIN AND T 12. D ATED N MOLD ALLIZI ERMIN MBER N A SY E EXP EC MC	RS. AN JALS. ERMIT ETAIL WITHI OR M ED TE AL TIF OF TE (MME) OSED 0220, E	NAL N S OF N THI ARKE RMIN C. ERMII TRIC, I HEA EXCE	S ARE TERME E ZON E ZON E D FE IAL AI IAL SIN AL FA T SIN PT E	E IN C ERIN MINAL IE INI ATUF ND IS ON E SHIO K SLU KPOS	G CC _ #11 DICA RE. ; MEA SACH N. JG A ; ED P	EES. INVEN DENT TED. SURE D AN	IFIER THE T ED BE D E S L AS	ARE ERMIN TWEE IDE RI THE T	NAL #1 N ESPEC	TIVEL	T3255-4 T3255-5 T3255N-1 T4055-1 T4055-2	3.00 3.00 3.40 3.40 *	3.10 3.10 3.50 3.50 *SEE C	3.20 3.20 3.60 3.60	3.00 3.00 3.40 3.40	3.10 3.10 3.50 3.50	3.20 3.20 3.60 3.60 TABLE	
1. DIM 2. ALL 3. N IS 3. N IS COI OP ⁻ IDE COI OP ⁻ IDE COI OP ⁻ IDE ON OP ⁻	DIME S THE E TERI NFORI TIONA ENTIFIE MENSIO 5 mm / AND N POPUI PLAN/ AWING 355-3 / RPAGI RKING	ENSION TOTA MINAL M TO L, BU ER MA ON 6 A AND 0 NE RE LATIO ARITY G CON AND T E SHA G IS FC	NS AF L NUM JESD T MUS NY BE APPLIE SFER T APPLIE APPL	RE IN I MBER DENTII 95-1 (37 BE EITHE ES TC M FR(0 TH POSSI IES T MS TC 3. DT EX CKAG	MILLIN OF TE FIER / SPP-0 LOCA ER A N MET. O MET. O THE D JEDE CEED	METER ERMIN AND T 12. D ATED V MOLD ALLIZI ERMIN MBER N A SY E EXP EC MC	RS. AN JALS. ERMIT ETAIL WITHI OR M ED TE AL TIF OF TE (MME OSED 0220, E mm.	IGLE S OF N THI ARKE RMIN C ERMIN TRIC, I HEA EXCE	S ARE NUMB TERN E ZON ED FE IAL AI NALS AL FA T SIN PT E) EREN	E IN C ERIN MINAL IE INI ATUF ND IS ON E SHIO K SLL KPOS	DEGR G CCC _ #11 I DICA RE I MEA EACH N. JG A ED P NLY.	EES. INVEN DENT TED. SURE D AN	IFIER THE T ED BE D E S L AS	ARE ERMIN TWEE IDE RI THE T	NAL #1 N ESPEC	TIVEL	T3255-4 T3255-5 T3255N-1 T4055-1 T4055-2	3.00 3.00 3.40 3.40 *	3.10 3.10 3.50 3.50 *SEE C	3.20 3.20 3.60 3.60 0MMON	3.00 3.00 3.40 3.40 JUMEN	3.10 3.10 3.50 3.50 ISIONS	3.20 3.20 3.60 3.60 TABLE	
1. DIM 2. ALL 3. N IS COP IDE IDE COP IDE IDE COP IDE IDE COP IDE IDE IDE IDE IDE IDE IDE IDE	DIME S THE E TERI NFORI TIONA NTIFIE MENSIO AND N POPUI PLAN/ AWING 355-3 / RKING MBER	ENSION TOTA MINAL MINAL MINAL BU ER MA ON 6 A AND 0 NE RE LATIO ARITY G CON ARITY G CON AND T E SHA G IS FC OF LE	NS AF L NUM JESD T MUS APPLIE APPLIE APPLIE APPL IFORM 2855-6 ALL NO DR PA EADS	RE IN I MBER DENTII 95-1 1 95-1 1 95-1 1 95-1 1 95-1 1 85-1 95-1 95-1 90-1 90-1 90-1 90-1 90-1 90-1 90-1 90	MILLIN OF TE SPP-0 LOCA ER A N MET. DM TE E NUT BLE IT D THE D THE CEED CEED CEED	METER ERMIN AND T 12. D ATED V MOLD ALLIZI ERMIN MBER N A SY E EXP E EXP E EXP E EXP E EXP E EXP E EXP	RS. AN JALS. ERMII ETAIL WITHI OR M ED TE AL TIF OF TE (MME' OSED 0220, E mm. (TON R REF	IGLE S OF N THI ARKE RMIN ERMIN TRIC, HEA EXCE	S ARE NUMB TERN E ZON ED FE IAL AI NALS AL FA AL FA T SIN PT E2 EREN NCE C	E IN C ERIN MINAL VE INI ATUF ND IS ON E SHIO K SLU K POS CE O DNLY.	DEGR G CCC _ #11 DICA RE HEACH N JG AS ED P	EES. NVEN DENT TED. SURE D AN S WEL	IFIER THE T D E S L AS MENS	ARE ERMIN TWEE IDE RI THE T SION F	NAL #1 N ESPEC	TIVEL	<u>T3255-4</u> <u>T3255-5</u> <u>T3255N-1</u> <u>T4055-1</u> <u>T4055-2</u>	3.00 3.00 3.00 3.40 3.40 *	3.10 3.10 3.50 3.50 SEE C	3.20 3.20 3.20 3.60 3.60 DMMON MON MON MON	3.00 3.00 3.40 3.40 3.40 DIMEN DIMEN	3.10 3.10 3.10 3.50 3.50 SIONS	3.20 3.20 3.20 3.60 3.60 TABLE	V, 5x5x0.

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600

27